

L-819SURKMGKW

HYPER RED

MEGA GREEN

Features

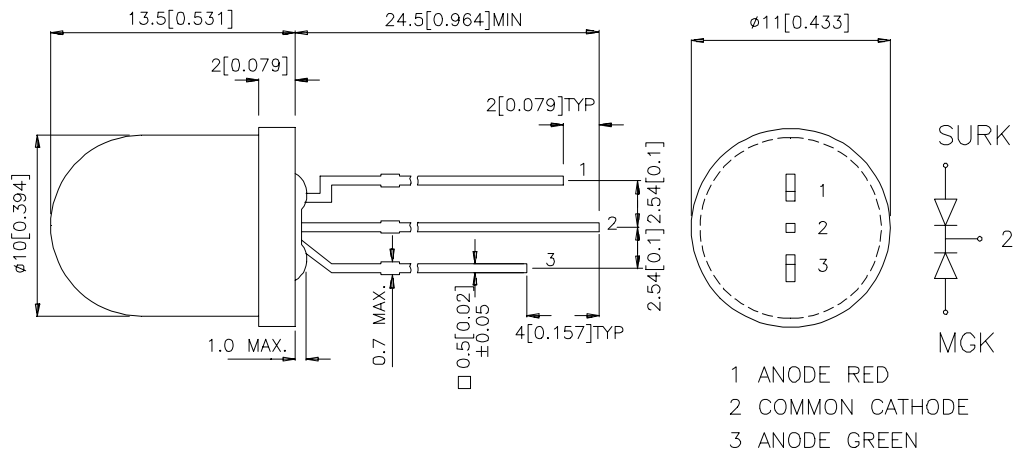
- UNIFORM LIGHT OUTPUT.
- LOW POWER CONSUMPTION.
- 3 LEADS WITH ONE COMMON CATHODE LEAD.
- I.C. COMPATIBLE.
- LONG LIFE - SOLID STATE RELIABILITY.

Description

The Hyper Red source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

The Mega Green source color devices are made with DH InGaAlP on GaAs substrate Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ± 0.25 (0.01") unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	2θ1/2
L-819SURKMGKW	HYPER RED (InGaAlP)	WHITE DIFFUSED	380	750	50°
	MEGA GREEN (InGaAlP)		50	130	

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

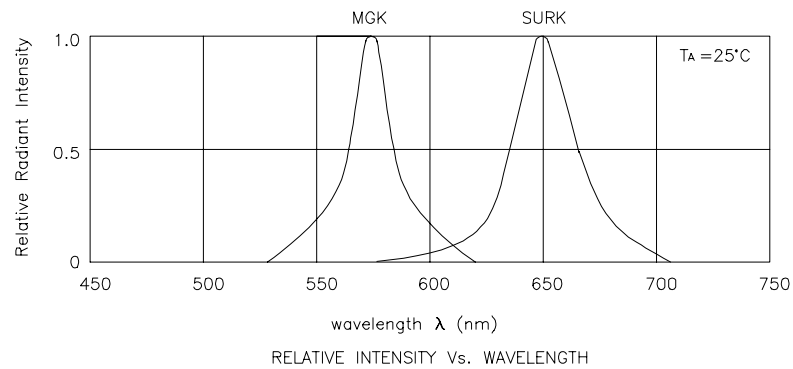
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	Hyper Red Mega Green	650 574		nm	I _F =20mA
λ _D	Dominate Wavelength	Hyper Red Mega Green	635 570		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	Hyper Red Mega Green	28 20		nm	I _F =20mA
C	Capacitance	Hyper Red Mega Green	35 15		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	Hyper Red Mega Green	1.95 2.1	2.5 2.5	V	I _F =20mA
I _R	Reverse Current	All		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

Parameter	Hyper Red	Mega Green	Units
Power dissipation	170	105	mW
DC Forward Current	30	30	mA
Peak Forward Current [1]	185	150	mA
Reverse Voltage	5		V
Operating/Storage Temperature	-40°C To +85°C		
Lead Soldering Temperature[2]	260°C For 5 Seconds		

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



Hyper Red / Mega Green L-819SURKMGKW

